



# PJP6NA90 / PJF6NA90 / PJZ6NA90

## 900V N-Channel MOSFET

**Voltage**

**900 V**

**Current**

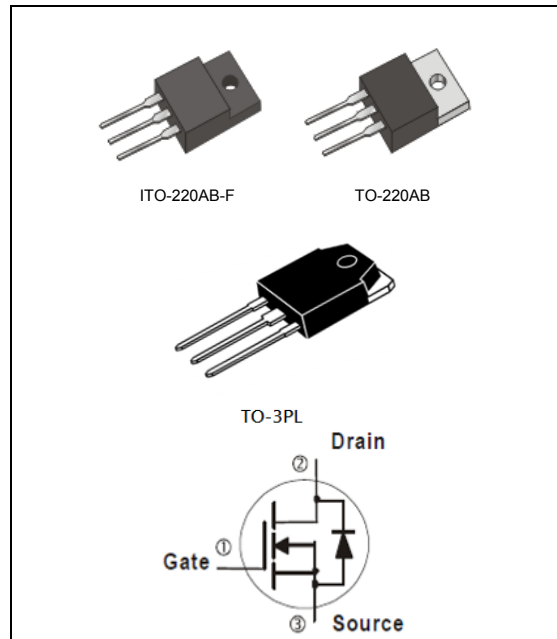
**6 A**

### Features

- $R_{DS(ON)}, V_{GS}@10V, I_D@3A < 2.3\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std.  
(Halogen Free)

### Mechanical Data

- Case : TO-220AB, ITO-220AB-F, TO-3PL Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-220AB Approx. Weight : 0.067 ounces, 1.89 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams
- TO-3PL Approx. Weight : 0.182 ounces, 5.174grams



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER                                         |                                 | SYMBOL          | TO-220AB | ITO-220AB-F | TO-3PL | UNITS               |
|---------------------------------------------------|---------------------------------|-----------------|----------|-------------|--------|---------------------|
| Drain-Source Voltage                              |                                 | $V_{DS}$        | 900      |             |        | V                   |
| Gate-Source Voltage                               |                                 | $V_{GS}$        | +30      |             |        | V                   |
| Continuous Drain Current                          |                                 | $I_D$           | 6        |             |        | A                   |
| Pulsed Drain Current                              |                                 | $I_{DM}$        | 24       |             |        | A                   |
| Single Pulse Avalanche Energy <sup>(Note 1)</sup> |                                 | $E_{AS}$        | 600      |             |        | mJ                  |
| Power Dissipation                                 | $T_C=25^\circ\text{C}$          | $P_D$           | 167      | 56          | 192    | W                   |
|                                                   | Derate above $25^\circ\text{C}$ |                 | 1.34     | 0.45        | 1.54   | W/ $^\circ\text{C}$ |
| Operating Junction and Storage Temperature Range  |                                 | $T_J, T_{STG}$  | -55~150  |             |        | $^\circ\text{C}$    |
| Typical Thermal resistance                        |                                 |                 |          |             |        |                     |
| -                                                 | Junction to Case                | $R_{\theta JC}$ | 0.75     | 2.23        | 0.65   | $^\circ\text{C/W}$  |
| -                                                 | Junction to Ambient             | $R_{\theta JA}$ | 62.5     | 120         | 50     |                     |

- Limited only By Maximum Junction Temperature



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### Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER                                             | SYMBOL       | TEST CONDITION                                         | MIN. | TYP.     | MAX.      | UNITS    |
|-------------------------------------------------------|--------------|--------------------------------------------------------|------|----------|-----------|----------|
| <b>Static</b>                                         |              |                                                        |      |          |           |          |
| Drain-Source Breakdown Voltage                        | $BV_{DSS}$   | $V_{GS}=0V, I_D=250\mu A$                              | 900  | -        | -         | V        |
| Gate Threshold Voltage                                | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$                          | 2    | 2.88     | 4         | V        |
| Drain-Source On-State Resistance                      | $R_{DS(on)}$ | $V_{GS}=10V, I_D=3A$                                   | -    | 1.85     | 2.3       | $\Omega$ |
| Zero Gate Voltage Drain Current                       | $I_{DSS}$    | $V_{DS}=900V, V_{GS}=0V$                               | -    | 0.02     | 1         | $\mu A$  |
| Gate-Source Leakage Current                           | $I_{GSS}$    | $V_{GS}=\pm 30V, V_{DS}=0V$                            | -    | $\pm 10$ | $\pm 100$ | nA       |
| Diode Forward Voltage                                 | $V_{SD}$     | $I_S=6A, V_{GS}=0V$                                    | -    | 0.86     | 1.4       | V        |
| <b>Dynamic</b> (Note 4)                               |              |                                                        |      |          |           |          |
| Total Gate Charge                                     | $Q_g$        | $V_{DS}=720V, I_D=6A,$<br>$V_{GS}=10V$ (Note 2,3)      | -    | 23.6     | -         | nC       |
| Gate-Source Charge                                    | $Q_{gs}$     |                                                        | -    | 5.4      | -         |          |
| Gate-Drain Charge                                     | $Q_{gd}$     |                                                        | -    | 9.2      | -         |          |
| Input Capacitance                                     | $C_{iss}$    | $V_{DS}=25V, V_{GS}=0V,$<br>$f=1.0\text{MHz}$          | -    | 915      | -         | pF       |
| Output Capacitance                                    | $C_{oss}$    |                                                        | -    | 101      | -         |          |
| Reverse Transfer Capacitance                          | $C_{rss}$    |                                                        | -    | 2.5      | -         |          |
| Turn-On Delay Time                                    | $t_{d(on)}$  | $V_{DD}=450V, I_D=6A,$<br>$R_G=25\Omega$<br>(Note 2,3) | -    | 17       | -         | ns       |
| Turn-On Rise Time                                     | $t_r$        |                                                        | -    | 28       | -         |          |
| Turn-Off Delay Time                                   | $t_{d(off)}$ |                                                        | -    | 66       | -         |          |
| Turn-Off Fall Time                                    | $t_f$        |                                                        | -    | 33       | -         |          |
| <b>Drain-Source Diode</b>                             |              |                                                        |      |          |           |          |
| Maximum Continuous Drain-Source Diode Forward Current | $I_S$        | ---                                                    | -    | -        | 6         | A        |
| Maximum Pulsed Drain-Source Diode Forward Current     | $I_{SM}$     | ---                                                    | -    | -        | 24        | A        |
| Reverse Recovery Time                                 | $t_{rr}$     | $V_{GS}=0V, I_S=6A$                                    | -    | 403      | -         | ns       |
| Reverse Recovery Charge                               | $Q_{rr}$     | $di_F/dt=100A/\mu s$ (Note 2)                          | -    | 6.1      | -         | $\mu C$  |

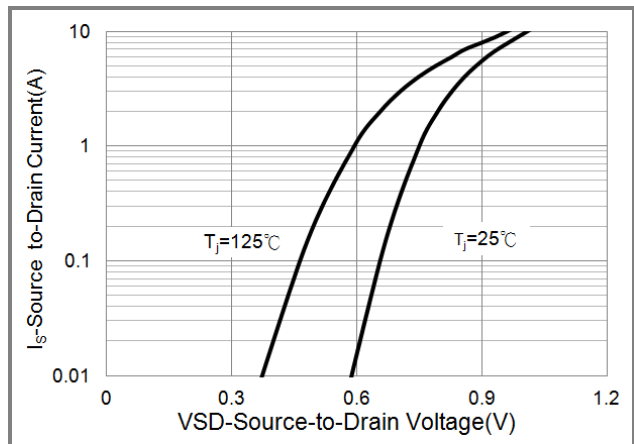
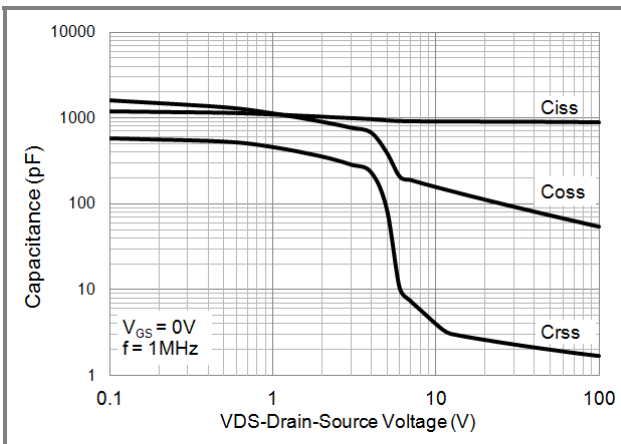
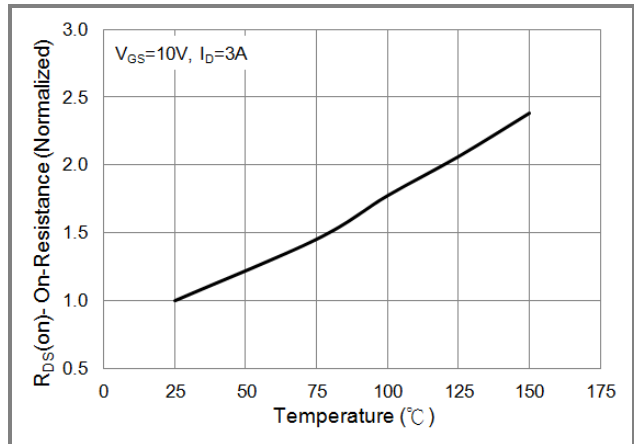
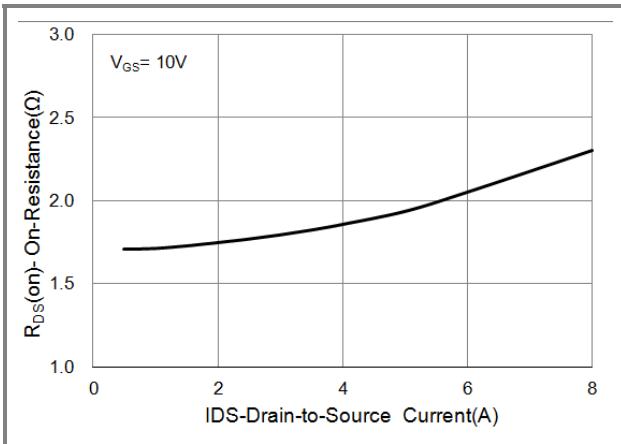
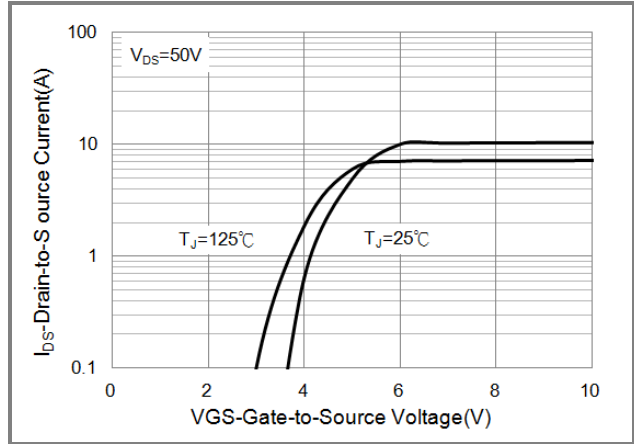
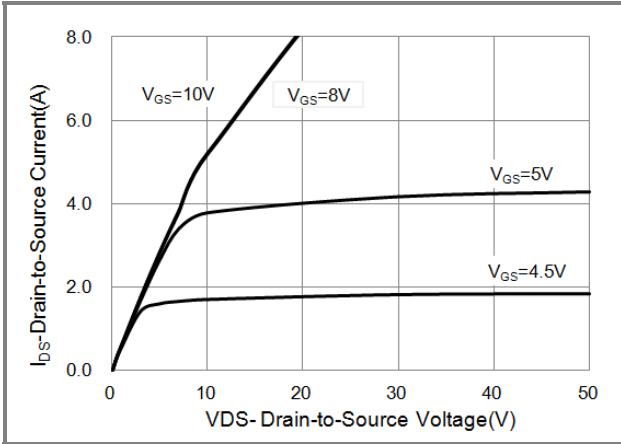
NOTES :

1.  $L=30\text{mH}, I_{AS}=6.2A, V_{DD}=50V, R_G=25\text{ohm}$ , Starting  $T_J=25^\circ\text{C}$
2. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
3. Essentially independent of operating temperature typical characteristics.
4. Guaranteed by design, not subject to production testing



# PJP6NA90 / PJF6NA90 / PJZ6NA90

## TYPICAL CHARACTERISTIC CURVES





# PJP6NA90 / PJF6NA90 / PJZ6NA90

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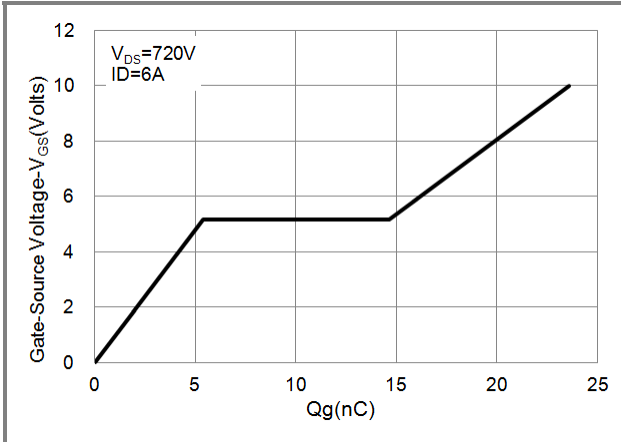


Fig.7 Gate Charge

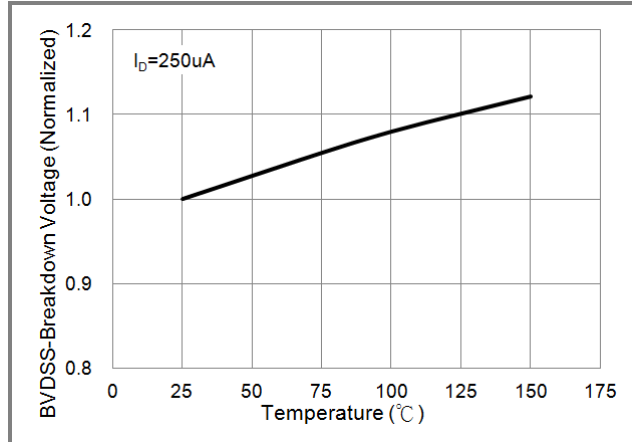


Fig.8 BV<sub>DSS</sub> vs. Junction Temperature

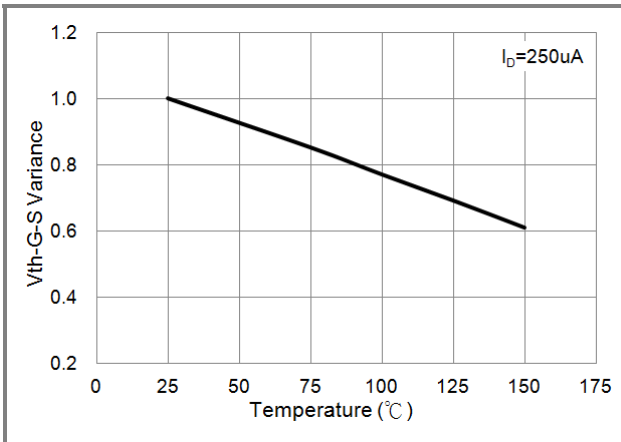


Fig.9 Threshold Voltage Variation with Temperature

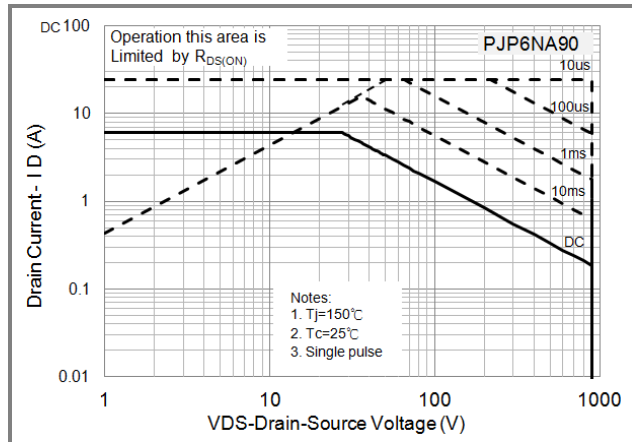


Fig.10 Maximum Safe Operating Area

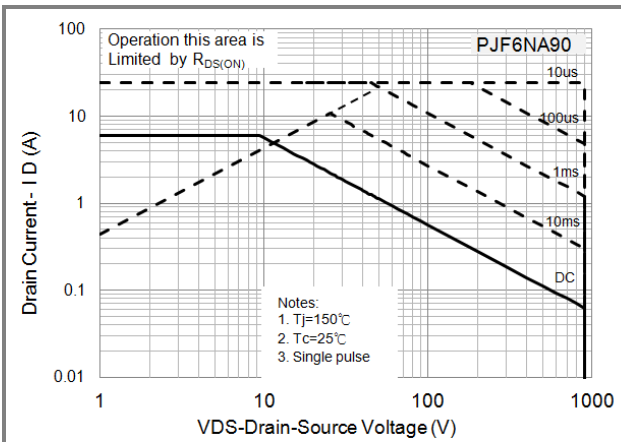


Fig.11 Maximum Safe Operating Area

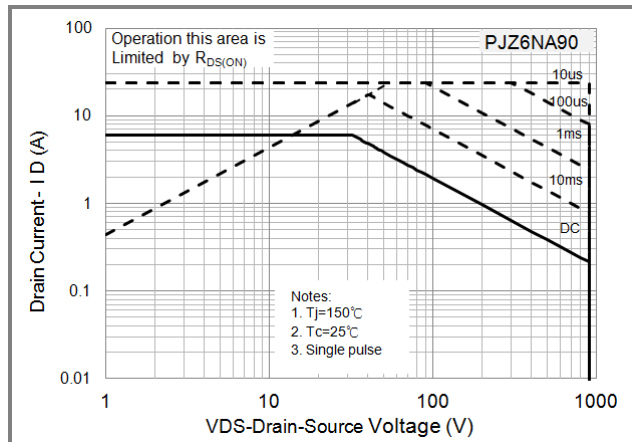


Fig.12 Maximum Safe Operating Area



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## TYPICAL CHARACTERISTIC CURVES

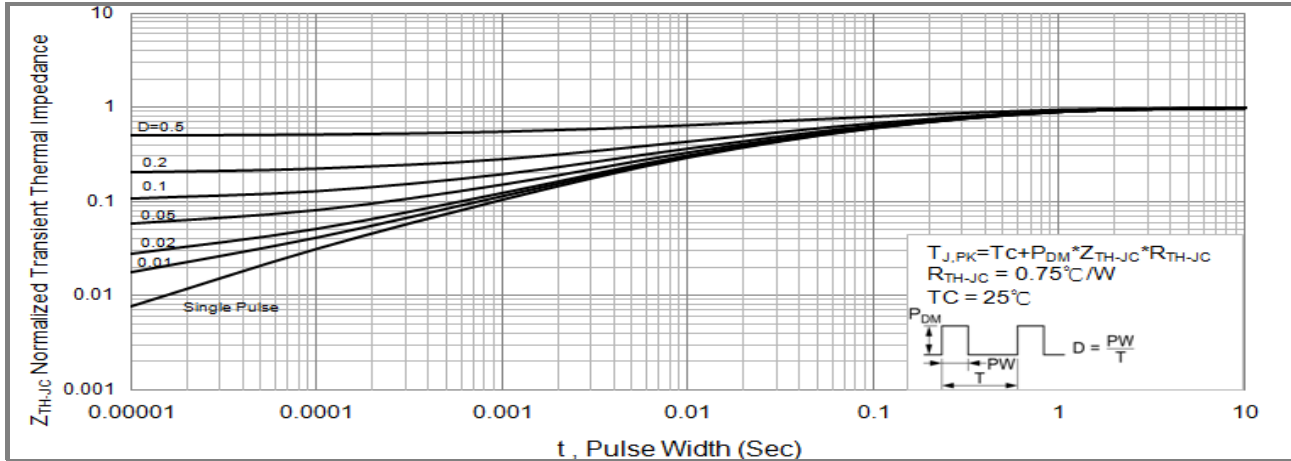


Fig.13 PJP6NA90 Normalized Transient Thermal Impedance vs. Pulse Width

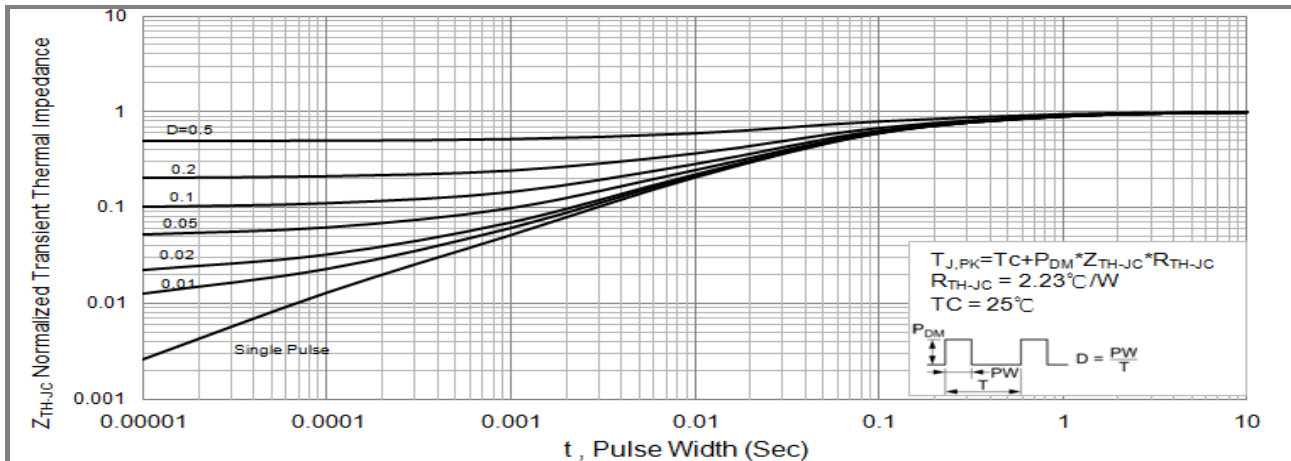


Fig.14 PJF6NA90 Normalized Transient Thermal Impedance vs. Pulse Width

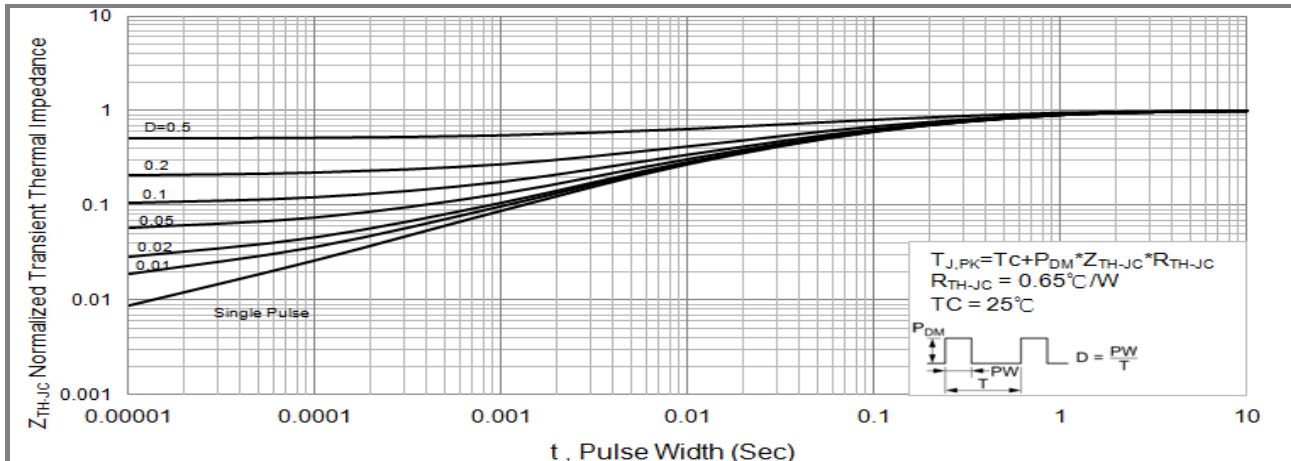
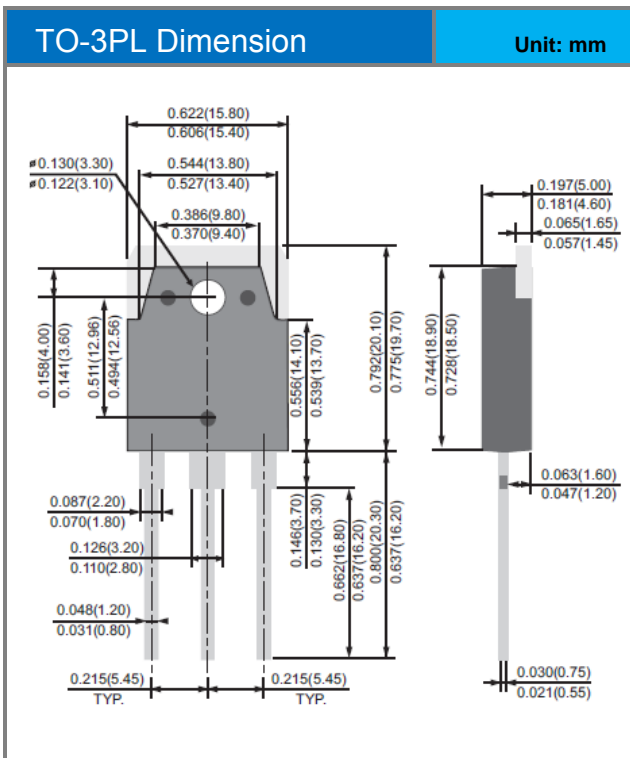
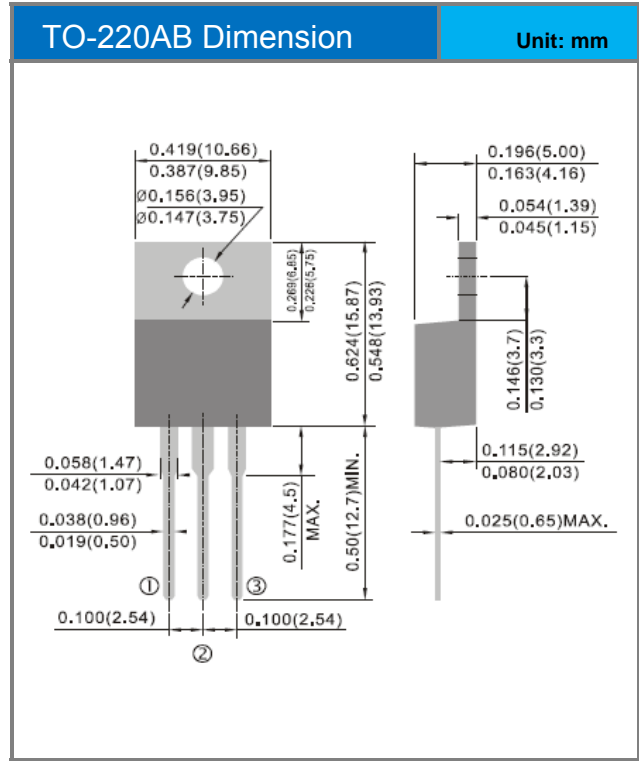
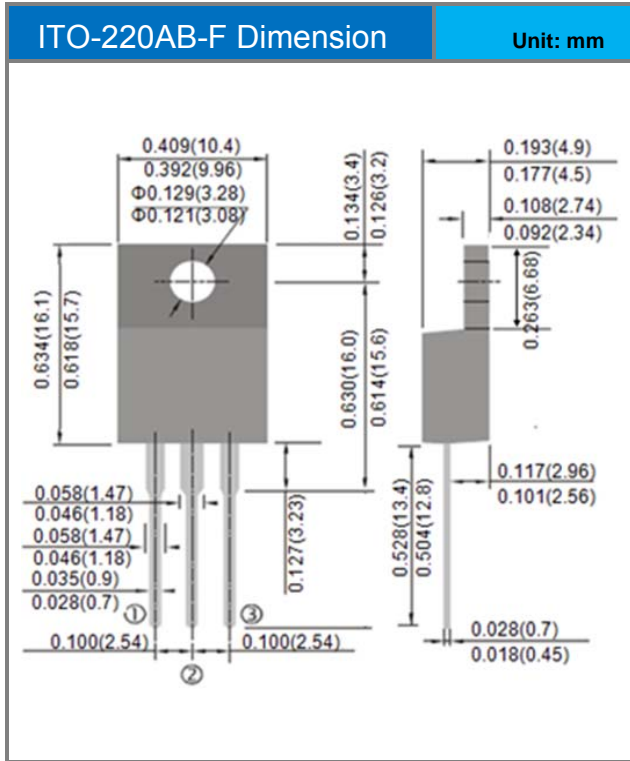


Fig.15 PJZ6NA90 Normalized Transient Thermal Impedance vs. Pulse Width



# PJP6NA90 / PJF6NA90 / PJZ6NA90

## Packaging Information





## PJP6NA90 / PJF6NA90 / PJZ6NA90

### PART NO PACKING CODE VERSION

| Part No Packing Code | Package Type | Packing type | Marking | Version      |
|----------------------|--------------|--------------|---------|--------------|
| PJP6NA90_TO_00001    | TO-220AB     | 50pcs / Tube | P6NA90  | Halogen free |
| PJF6NA90_TO_00001    | ITO-220AB-F  | 50pcs / Tube | F6NA90  | Halogen free |
| PJZ6NA90_TO_10001    | TO-3PL       | 30pcs / Tube | Z6NA90  | Rohs         |



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